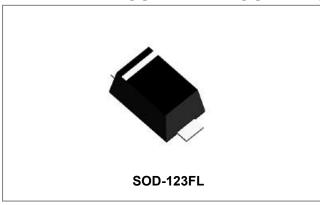






US1AL THRU US1ML SURFACE MOUNT HIGH EFFICIENCY RECTIFIER



Features

- Glass passivated device
- Ideal for surface mouted applications
- Low reverse leakage
- Metallurgically bonded construction
- High temperature soldering guaranteed: 260 C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) Tension
- Plastic material-UL flammability 94V-0
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: SOD-123FL molded plastic
- Terminals: Plated leads solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.0007 ounce, 0.02 grams

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

| Characteristic | Symbol | US1AL | US1BL | US1DL | US1GL | US1JL | US1KL | US1ML | Units |
|--|---|-------------|-------|-------|----------|-------|-------|-------|-------|
| Marking | | UA | UB | UD | UG | UJ | UK | UM | |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage | V _{RSM} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | |
| Average Rectified Output Current @T _A =30 °C | Io | 1.0 | | | | Α | | | |
| Peak Forward Surge Current 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method) | I _{FSM} | 30 | | | | Α | | | |
| Forward Voltage per element @I _F =1.0A | V _F | | 1 | | 1.4 | | 1.7 | | V |
| Peak Reverse Current @T _A =25°C At Rated DC Blocking Voltage @T _A =100°C | I _R | | | | 5 100 | | | | μΑ |
| Maximum Reverse Recovery Time (NOTE 1) | Trr | 50 75 | | | ns | | | | |
| Typical Thermal Resistance | R _{⊝JA} | 180 | | | | K/W | | | |
| Operating Junction and Storage Temperature Range | T_{J} , T_{STG} | -55 to +150 | | | | °C | | | |

Note: 1.Measured with I_F =0.5A, I_R =1.0A, I_{rr} =0.25A

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Ratings and Characteristics Curves

FIG. 1- FORWARD CURRENT DERATING CURVE

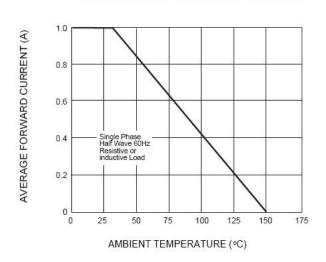


FIG. 2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

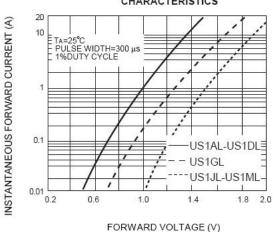
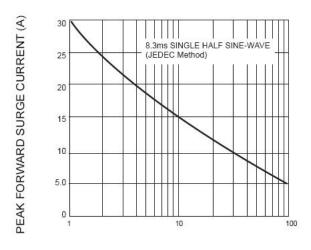
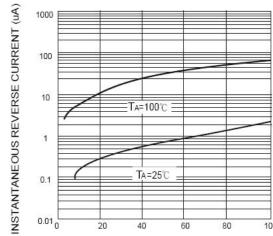


FIG. 3-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



NUMBER OF CYCLES AT 60 Hz





PERCENT OF RATED PEAK REVERSE VOLYAGE(%)

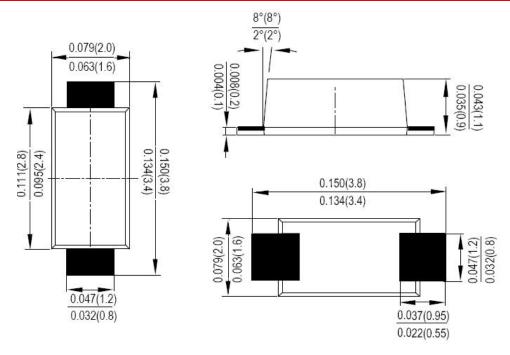
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Mechanical Dimensions SOD-123FL(Inches/Millimeters)



Ordering Information

| Device | Package | Shipping | | | |
|----------------------------|-----------|----------------|--|--|--|
| US1AL THRU US1ML | SOD-123FL | 3000pcs / reel | | | |
| US1ALTR THRU US1MLTR | SOD-123FL | 3000pcs / reel | | | |

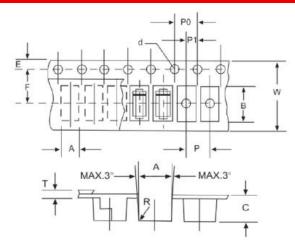
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



UA = Marking code

Carrier Tape Specification SOD-123FL



| SYMBOL | Millimeters | | | | |
|---------|-------------|------|--|--|--|
| STWIBOL | Min. | Max. | | | |
| Α | 1.95 | 2.15 | | | |
| В | 3.85 | 4.05 | | | |
| С | 1.35 | 1.55 | | | |
| d | 1.50 | 1.60 | | | |
| E | 1.65 | 1.85 | | | |
| F | 3.40 | 3.60 | | | |
| Р | 3.90 | 4.10 | | | |
| P0 | 3.90 | 4.10 | | | |
| P1 | 1.90 | 2.10 | | | |
| W | 7.90 | 8.30 | | | |

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